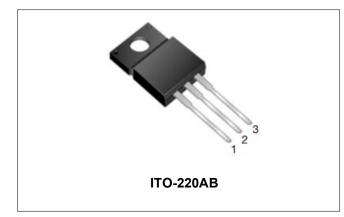


MBRF30200CTR

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MBRF30200CTR SCHOTTKY RECTIFIER



Features

- 150°C T_J operation
- Center tap configuration
- Low forward voltage drop
- High purity, high temperature epoxy encapsulation for enhanced mechanical strength and moisture resistance
- High frequency operation
- Guard ring for enhanced ruggedness and long term reliability
- Terminals finish: 100% Pure Tin
- This is a Pb Free Device
- All SMC parts are traceable to the wafer lot
- Additional testing can be offered upon request

Circuit Diagram



Applications

- Switching power supply
- Converters
- Free-Wheeling diodes
- Reverse battery protection

Maximum Ratings(limiting values, at 25 °C unless otherwise specified)

Characteristics	Symbol	Condition	Max.	Units
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	V _{RRM} V _{RWM} V _R	-	200	V
Average Rectified Forward Current	I _{F (AV)}	Tc=100°C, In DC	15(Per Leg) 30(Per Device)	А
Peak One Cycle Non-Repetitive Surge Current(Per Leg)	I _{FSM}	8.3ms, Half Sine pulse	200	А

Electrical Characteristics:

Characteristics	Symbol	Condition	Тур.	Max.	Units
Forward Voltage Drop(Per Leg)*	o(Per Leg)* V _{F1} @ 15A, Pulse, T _J = 25 °C		0.89	0.95	V
	V _{F2}	@ 15A, Pulse, T _J = 125 °C	0.77	0.80	V
Reverse Current(Per Leg)*	I _{R1}	$@V_R = rated V_{R,} T_J = 25 \ ^{\circ}C$	0.0002	1.0	mA
	I _{R2}	@V _R = rated V _R , T _J = 125 °C	0.001	6.0	mA
Junction Capacitance(Per Leg)	Ст	@V _R = 5V, T _C = 25 °C, f _{SIG} = 1MHz	208	250	pF
Series Inductance(Per Leg)	Ls	Measured lead to lead 5 mm from package body	8.0	-	nH
Voltage Rate of Change	dv/dt	-	-	10,000	V/μs
RSM Isolation Voltage (t = 1.0 second, R. H. < =30%, $T_A = 25 \text{ °C}$)	V _{ISO}	Clip mounting, the epoxy body away from the heatsink edge by more than 0.110" along the lead direction.	-	4500	V
		Clip mounting, the epoxy body is inside the heatsink.	-	3500	
		Screw mounting, the epoxy body is inside the heatsink.	-	1500	

* Pulse width < 300 µs, duty cycle < 2%

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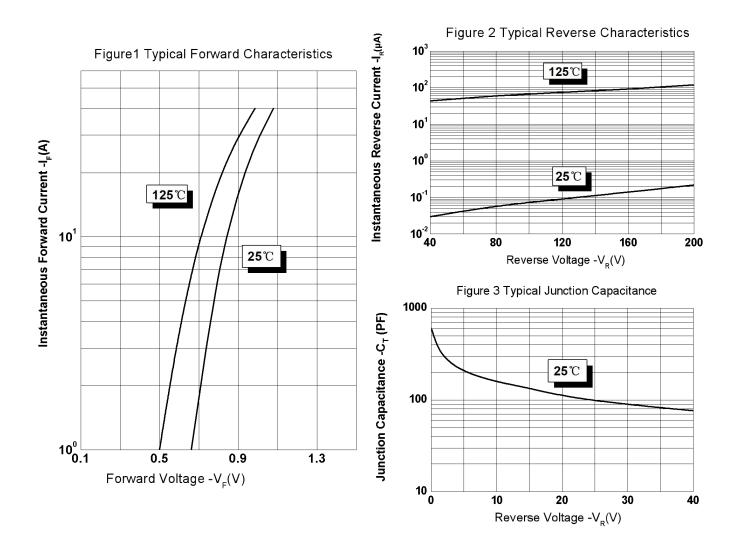
MBRF30200CTR

RoHS 🗭

Thermal-Mechanical Specifications:

Characteristics	Symbol	Condition	Specification	Units
Junction Temperature	TJ	-	-55 to +150	°C
Storage Temperature	T _{stg}	-	-55 to +150	°C
Typical Thermal Resistance Junction to Case(Per Leg)	$R_{ ext{ heta}JC}$	DC operation	3.5	°C/W
Approximate Weight	wt	-	2	g
Case Style	ITO-220AB			

Ratings and Characteristics Curves





MBRF30200CTR

Millimeters

TYP.

4.50

1.30

3.00 2.70

0.60

1.20

1.60

1.30

1.70

0.60

15.00

10.16

2.55

5.10

6.70 13.20

1.80

1.00

0.80

3.50

3.19 2.70 5° 4°

10°

<u>5°</u> 5°

MIN.

4.30

1.10

2.80

2.50

0.50

1.10

1.50

1.20

1.60

0.50

14.80

9.96

6.50 12.70

1.60

0.80

0.60

3.30

<u>2.99</u> 2.50

F

30

200

CTR

SSG

YΥ

ww

L

RoHS 🗭

MAX.

4.70

1.50 3.20 2.90

0.75

1.35

1.75

1.45

1.85

0.75 15.20

10.36

6.90

13.70

2.00

1.20

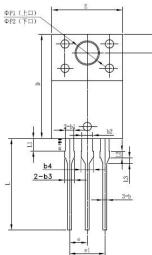
1.00 3.70

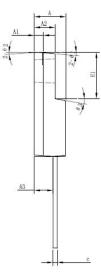
3.39 2.90

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Mechanical Dimensions ITO-220AB

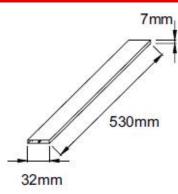
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1		1	

Tube Specification



Marking Diagram

SYMBOL

А

<u>A1</u>

<u>A2</u>

<u>A3</u> b

b1

b2

b3

<u>b4</u>

С

D

F

е

e1

H1

L1

L2 L3

ΦΡ1(上口)

ΦΡ2(下口)

Q 01 02

<u>Θ3</u> Θ4

Θ5

MBRF30200CTR SSG XXXXX

Where XXXXX is YYWWL

MBR = Device Type

- = Package type
 - = Forward Current (30A) = Reverse Voltage (200V)
- = Configuration
- = SSG = Year

= Week

= Lot Number

Cautions: Molding resin Epoxy resin UL:94V-0

Ordering Information

Device	Package	Shipping
MBRF30200CTR	ITO-220AB (Pb-Free)	50 pcs/ tube

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MBRF30200CTR



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